



SEMCO LASER TECHNOLOGY*

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LD – 710A

Visible Laser Diode Technical Data

ABSOLUTE MAXIMUM RATINGS (T_c=25°C)

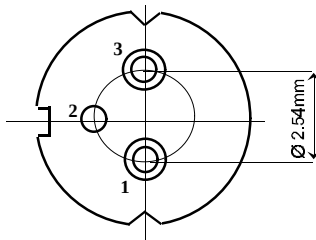
- Index Guided MQW Structure
- Wavelength : 780 nm (Typ.)
- Optical Power : 10 mW CW
- Threshold Current : 45 mA (Typ.)
- Standard Package : 9.0 mm Ø

DESCRIPTION	SYMBOL	RATED VALUE
Optical power (mW)	PO	10
Operation Temperature (°C)	Top	-10 to +40
Storage Temperature (°C)	Tstg	-40 to +85
LD reverse voltage (V)	VLDR	2
PD reverse voltage (V)	VPDR	30

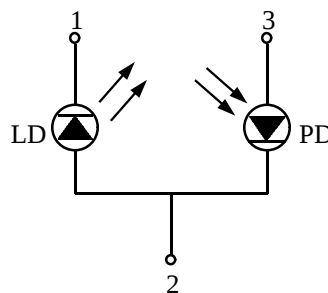
OPTICAL AND ELECTRICAL CHARACTERISTICS (T_c=25°C)

DESCRIPTION	SYMBOL	MIN.	TYPICAL	MAX.	TEST CONDITION
Lasing Wavelength (nm)	λ_p	770	780	790	P _o =10mW
Threshold Current (mA)	I _{th}	15	25	40	P _o =10mW
Operation Current (mA)	I _{op}	30	40	60	P _o =10mW
Operation Voltage (V)	V _{op}	2.0	2.4	2.7	P _o =10mW
Monitor Current (µA)	I _m	10	30	90	P _o =10 mW, V _R =5V
Slope Efficiency (mW/mA)	ζ	0.4	0.5	0.7	***
Beam Divergence // (°)	$\theta_{//}$	8	10	11	P _o =10mW
Beam Divergence ⊥ (°)	$\theta_{\perp}$	25	31	40	P _o =10mW
Astigmatism (µm)	A _s	***	11	***	P _o =10mW, NA=0.4

Bottom View Pin Location



PIN CONNECTION



1. Laser diode cathode

2. Laser diode anode
photodiode cathode

3. Photodiode anode

case and pin no. 2 are in common